

<b>PATENT ASSIGNMENT COVER SHEET</b>
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Electronic Version v1.1  
 Stylesheet Version v1.2

EPAS ID: PAT5186398

<b>SUBMISSION TYPE:</b>	NEW ASSIGNMENT
<b>NATURE OF CONVEYANCE:</b>	ASSIGNMENT
<b>CONVEYING PARTY DATA</b>	
<b>Name</b>	<b>Execution Date</b>
CHENG-YEN TSAI	10/09/2018
<b>RECEIVING PARTY DATA</b>	
<b>Name:</b>	TAIWAN SEMICONDUCTOR MANUFACTURING
<b>Street Address:</b>	NO. 8, LI-HSIN RD. 6
<b>Internal Address:</b>	HSINCHU SCIENCE PARK
<b>City:</b>	HSINCHU
<b>State/Country:</b>	TAIWAN
<b>Postal Code:</b>	300-78
<b>PROPERTY NUMBERS Total: 1</b>	
<b>Property Type</b>	<b>Number</b>
<b>Application Number:</b>	15952534
<b>CORRESPONDENCE DATA</b>	
<b>Fax Number:</b>	(972)732-9218
<i>Correspondence will be sent to the e-mail address first; if that is unsuccessful, it will be sent using a fax number, if provided; if that is unsuccessful, it will be sent via US Mail.</i>	
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<b>Correspondent Name:</b>	SLATER MATSIL, LLP/TSMC
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<b>ATTORNEY DOCKET NUMBER:</b>	TSMP20172476US00
<b>NAME OF SUBMITTER:</b>	KAREN VERTZ
<b>SIGNATURE:</b>	/Karen Vertz/
<b>DATE SIGNED:</b>	10/12/2018
<b>Total Attachments: 2</b>	
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Atty Dkt No.: TSMC/P20172476US

**ASSIGNMENT FOR APPLICATION FOR PATENT**

WHEREAS:

Names and Addresses of Inventors:

1)	Zoe CHEN No. 8, Li-Hsin Rd. 6 Hsinchu Science Park Hsinchu 300-78 TAIWAN ROC	2)	Ching-Hwanq SU No. 8, Li-Hsin Rd. 6 Hsinchu Science Park Hsinchu 300-78 TAIWAN ROC
3)	Cheng-Lung HUNG No. 8, Li-Hsin Rd. 6 Hsinchu Science Park Hsinchu 300-78 TAIWAN ROC	4)	Cheng-Yen TSAI No. 8, Li-Hsin Rd. 6 Hsinchu Science Park Hsinchu 300-78 TAIWAN ROC
5)	Da-Yuan LEE No. 8, Li-Hsin Rd. 6 Hsinchu Science Park Hsinchu 300-78 TAIWAN ROC	6)	Hsin-Yi LEE No. 8, Li-Hsin Rd. 6 Hsinchu Science Park Hsinchu 300-78 TAIWAN ROC
7)	Weng CHANG No. 8, Li-Hsin Rd. 6 Hsinchu Science Park Hsinchu 300-78 TAIWAN ROC	8)	Wei-Chin LEE No. 8, Li-Hsin Rd. 6 Hsinchu Science Park Hsinchu 300-78 TAIWAN ROC

(hereinafter referred to as Assignors), have invented a certain invention entitled:

**METHODS FOR THRESHOLD VOLTAGE TUNING AND STRUCTURES FORMED THEREBY**

enclosed herewith; and

WHEREAS, Taiwan Semiconductor Manufacturing Co., Ltd., having a place of business at No. 8, Li-Hsin Rd. 6, Hsinchu Science Park, Hsinchu 300-78, TAIWAN ROC (hereinafter referred to as Assignee), is desirous of acquiring the entire right, title and interest in and to said application (hereinafter referred to as Application), and the invention disclosed therein (hereinafter referred to as Invention), and in and to all embodiments of the Invention, heretofore conceived, made or discovered by said Assignors, and in and to any and all patents, inventor's certificates and other forms of protection (hereinafter referred to as Patents) thereon granted in any and all countries and groups of countries.

NOW, THEREFORE, in consideration of good and valuable consideration acknowledged by said Assignors to have been received in full from said Assignee:

1. Said Assignors hereby sell, assign, transfer and convey to Assignee the full and exclusive right, title and interest (a) in and to said Application and said Invention; (b) in and to all rights to apply for patents on said Invention in any and all countries pursuant to the International Convention for the Protection of Industrial Property or otherwise; (c) in and to any and all Applications filed and any and all Patents granted on said Invention in any and all countries and groups of countries, including each and every Application filed and each and every Patent granted on any application which is a conventional, division, substitution, or continuation of said Application; and (d)

in and to each and every reissue or extension of any of said Patents.

2. Said Assignors hereby covenant and agree to cooperate with said Assignee to enable said Assignee to enjoy to the fullest extent the right, title and interest to said Invention herein conveyed in any and all countries and groups of countries. Such cooperation by said Assignors shall include prompt production of pertinent facts and documents, giving testimony, execution of petitions, oaths, specifications, declarations or other papers, and other assistance all to the extent deemed necessary or desirable by said Assignee (a) for perfecting in said Assignee the right, title and interest herein conveyed; (b) for prosecuting any of said applications; (c) for filing and prosecuting substitute, conventional, divisional, continuing or additional applications covering said Invention; (d) for filing and prosecuting applications for reissuance of any of said Patents; (e) for interference or other priority proceedings involving said Invention; and (f) for legal proceedings involving said Invention and any application therefore and any Patents granted thereon, including without limitation opposition proceedings, cancellation proceedings, priority contests, public use proceedings, infringement actions and court actions; provided, however, that the expense incurred by said Assignors in providing such cooperation shall be paid for by said Assignee.

3. The term and covenants of this agreement shall inure to the benefit of said Assignee, its successors, assigns and other legal representatives, and shall be binding upon said Assignors, their respective heirs, legal representatives and assigns.

4. Said Assignors hereby warrant and represent that they have not entered and will not enter into any assignment, contract, or understanding in conflict herewith.

IN WITNESS WHEREOF, the said Assignors have executed and delivered this instrument to said Assignee on the dates indicated below.

1) \_\_\_\_\_ (DATE) Zoe CHEN

2) \_\_\_\_\_ (DATE) Ching-Hwang SU

3) \_\_\_\_\_ (DATE) Cheng-Lung HUNG

4) 2018.10.9 (DATE) Cheng-Yen TSAI  
Cheng-Yen TSAI

5) \_\_\_\_\_ (DATE) Da-Yuan LEE

6) \_\_\_\_\_ (DATE) Hsin-Yi LEE